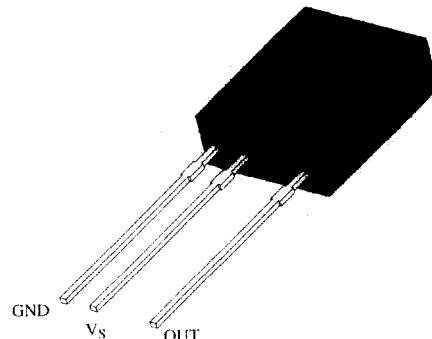


## Photo Modules for PCM Remote Control Systems

### Available types for different carrier frequencies

| Type     | f <sub>0</sub> | Type     | f <sub>0</sub> |
|----------|----------------|----------|----------------|
| TSOP1130 | 30 kHz         | TSOP1133 | 33 kHz         |
| TSOP1136 | 36 kHz         | TSOP1137 | 36.7 kHz       |
| TSOP1138 | 38 kHz         | TSOP1140 | 40 kHz         |
| TSOP1156 | 56 kHz         |          |                |



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### Description

The TSOP11.. series are miniaturized receivers for infrared remote control systems. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter. The demodulated output signal can directly be decoded by a microprocessor.

The main benefit is the operation with short burst transmission codes (e.g. RECS 80) and high data rates.

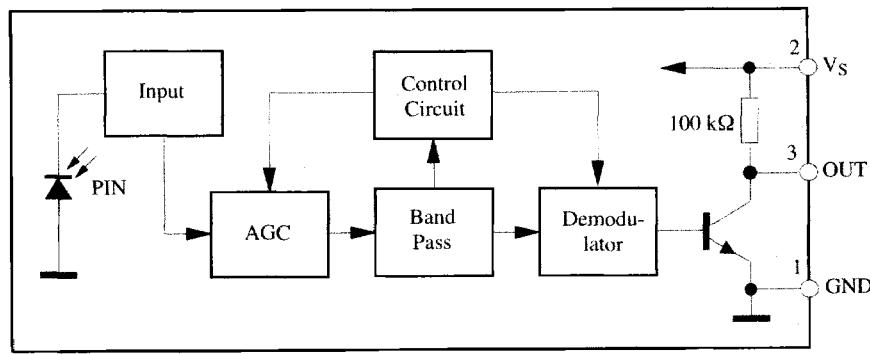
### Features

- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against electrical field disturbance
- TTL and CMOS compatibility
- Output active low
- Low power consumption
- High immunity against ambient light

### Special Features

- Enhanced data rate of 2400 bit/s
- Operation with short bursts possible  
(≥6 cycles/burst)

### Block Diagram



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# TSOP11..

## Absolute Maximum Ratings

T<sub>amb</sub> = 25°C

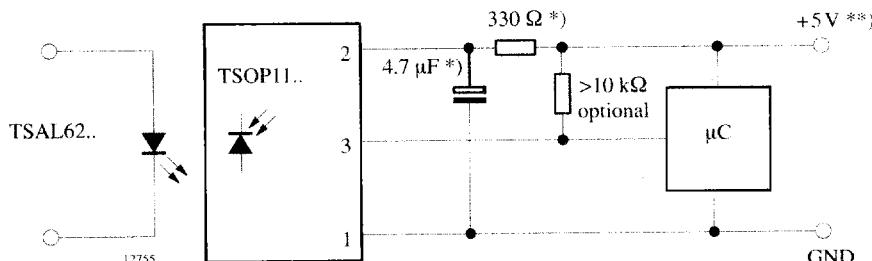
| Parameter                   | Test Conditions            | Symbol           | Value      | Unit |
|-----------------------------|----------------------------|------------------|------------|------|
| Supply Voltage              | (Pin 2)                    | V <sub>S</sub>   | -0.3...6.0 | V    |
| Supply Current              | (Pin 2)                    | I <sub>S</sub>   | 5          | mA   |
| Output Voltage              | (Pin 3)                    | V <sub>O</sub>   | -0.3...6.0 | V    |
| Output Current              | (Pin 3)                    | I <sub>O</sub>   | 5          | mA   |
| Junction Temperature        |                            | T <sub>j</sub>   | 100        | °C   |
| Storage Temperature Range   |                            | T <sub>stg</sub> | -25...+85  | °C   |
| Operating Temperature Range |                            | T <sub>amb</sub> | -25...+85  | °C   |
| Power Consumption           | (T <sub>amb</sub> ≤ 85 °C) | P <sub>tot</sub> | 50         | mW   |
| Soldering Temperature       | t ≤ 10 s, 1 mm from case   | T <sub>sd</sub>  | 260        | °C   |

## Basic Characteristics

T<sub>amb</sub> = 25°C

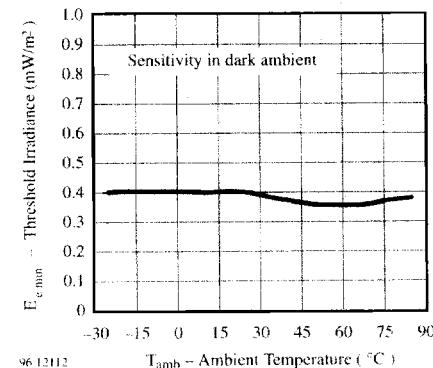
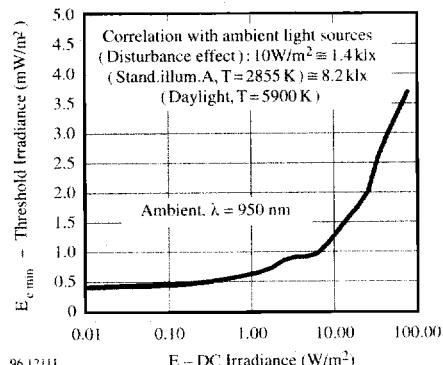
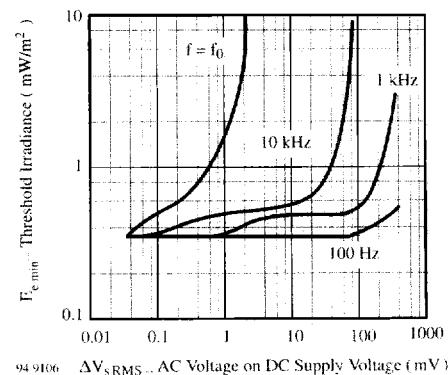
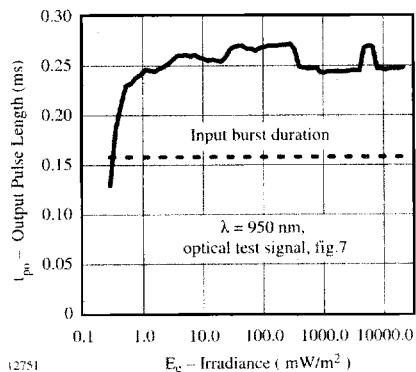
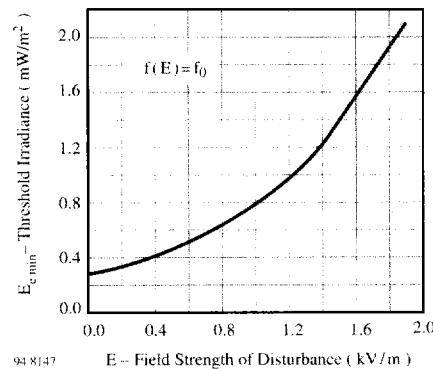
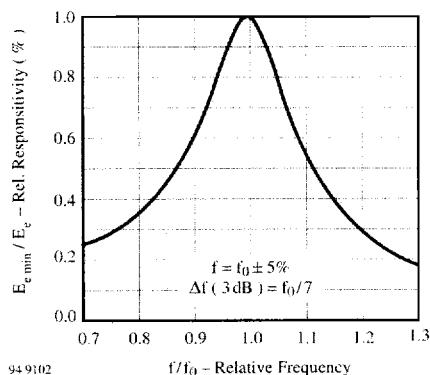
| Parameter                  | Test Conditions  | Symbol             | Min | Typ  | Max | Unit              |
|----------------------------|--|--------------------|-----|------|-----|-------------------|
| Supply Current (Pin 2)     | V <sub>S</sub> = 5 V, E <sub>v</sub> = 0   | I <sub>SD</sub>    | 0.4 | 0.5  | 0.8 | mA                |
|                            | V <sub>S</sub> = 5 V, E <sub>v</sub> = 40 klx, sunlight  | I <sub>SH</sub>    |     | 1    |     | mA                |
| Transmission Distance      | E <sub>v</sub> = 0, test signal see fig.8, IR diode TSIP5201, I <sub>F</sub> = 0.4 A                           | d                  |     | 35   |     | m                 |
| Output Voltage Low (Pin 3) | I <sub>OSL</sub> = 0.5 mA, E <sub>c</sub> = 0.7 mW/m <sup>2</sup> , f = f <sub>0</sub> , test signal see fig.7 | V <sub>OSL</sub>   |     |      | 250 | mV                |
| Irradiance (30 – 40 kHz)   | Test signal see fig.7  | E <sub>e</sub> min |     | 0.4  | 0.6 | mW/m <sup>2</sup> |
|                            | Test signal see fig.8  | E <sub>e</sub> min |     | 0.35 | 0.5 | mW/m <sup>2</sup> |
| Irradiance (56 kHz)        | Test signal see fig.7  | E <sub>e</sub> min |     | 0.45 | 0.7 | mW/m <sup>2</sup> |
|                            | Test signal see fig.8  | E <sub>e</sub> min |     | 0.40 | 0.6 | mW/m <sup>2</sup> |
| Irradiance                 | Test signal see fig.7  | E <sub>e</sub> max | 30  |      |     | W/m <sup>2</sup>  |
| Directivity                | Angle of half transmission distance  | Φ <sub>1/2</sub>   |     | ±45  |     | deg               |

## Application Circuit



\*) only necessary to suppress power supply disturbances  
\*\*) tolerated supply voltage range : 4.5 V < V<sub>S</sub> < 5.5 V

**Typical Characteristics** ( $T_{amb} = 25^\circ C$  unless otherwise specified)



# TSOP11..

**TEMIC**  
Semiconductors

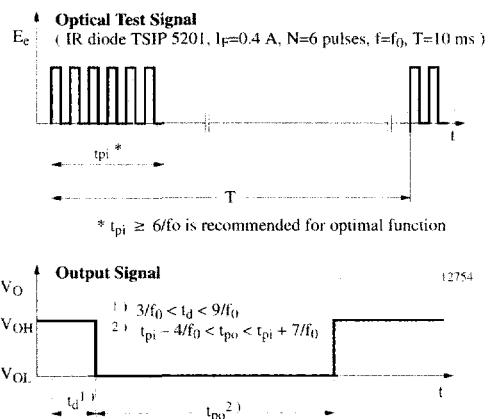


Figure 7. Output Function

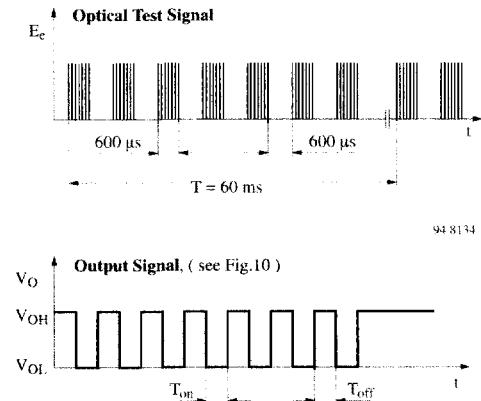


Figure 8. Output Function

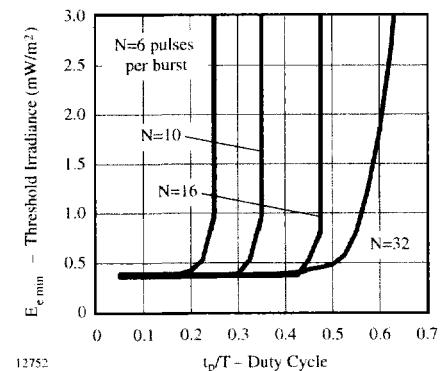


Figure 9. Sensitivity vs. Duty Cycle

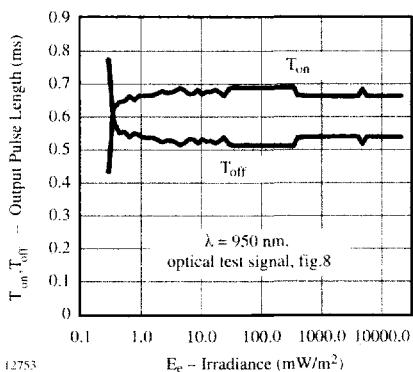


Figure 10. Output Pulse Diagram

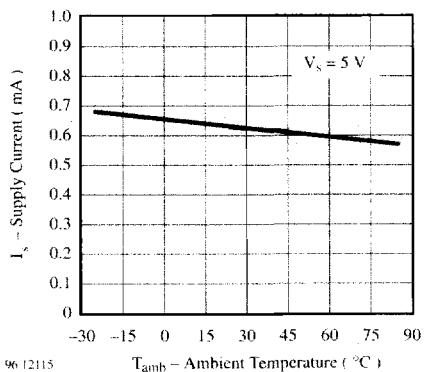


Figure 11. Supply Current vs. Ambient Temperature

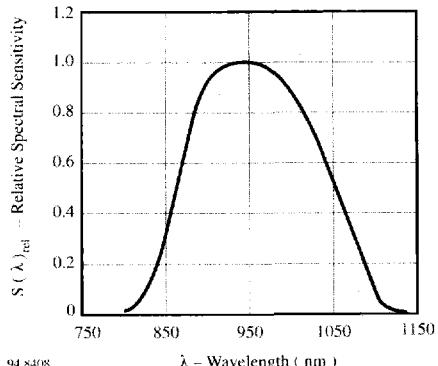


Figure 12. Relative Spectral Sensitivity vs. Wavelength

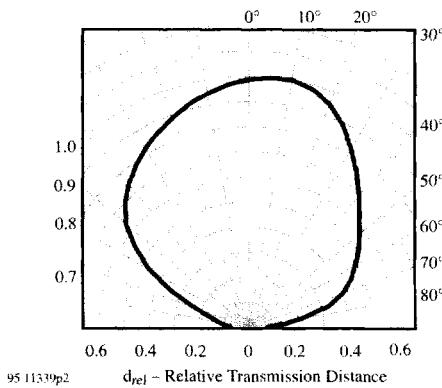


Figure 13. Vertical Directivity  $\phi_y$

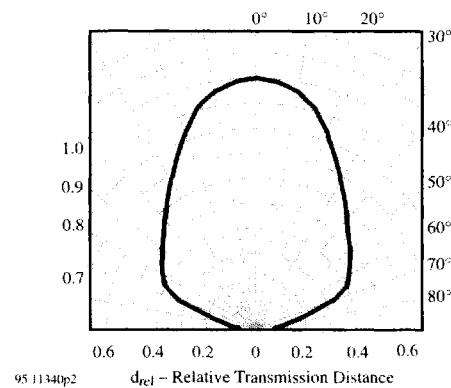


Figure 14. Horizontal Directivity  $\phi_x$

### Dimensions in mm

